

# **GATE** activities @ IPHC

GATE technical meeting – Jan. 2020

Speaker : Clément Corneille

### Summary

#### I. GATE activities @ IPHC

#### **II. Proton recoil telescope**

- 1. Characteristics
- 2. GATE modelization
- 3. Spectrum example
- 4. Background study

#### **III. Applications & prospect**

# I. GATE activites @ IPHC

- Organ dose calculations in interventional radiology
- How accurate are organ dose softwares / measurements?
- How sensitive are dose calculations to different parameters?





- Airborne gamma spectrometry
- Development of a drone-borne gamma spectrometry system
- Data analysis based on machine learning and Monte Carlo simulations (GATE)





#### **1.** Characteristics

 $\rightarrow$  **neutron** detector produced in collaboration with IRSN

 $\rightarrow$  goal : measurement of neutrons energy from 5 to 20 MeV

Compact device !





#### **II. Proton recoil telescope** 1. Characteristics

 $\rightarrow$  detection principle : convert the neutron into a proton



This PRT is able to measure neutrons energy in the 5-30 MeV range

#### 2. GATE modelization

#### $\rightarrow$ GATE simulation of the detector to :

- validate the analysis code
- evaluate its performances

• test its response to various spectra of neutrons (energy resolution, efficiency correction, background, ...) and to different parameters (converter thickness, material choice, ...)



GATE simulation (PCBs and Aluminium box not displayed)

3. Spectrum example

Raw spectrum of a GATE simulated mono-energetic neutron beam of 20 MeV  $\Phi = 10^7 \text{ n.cm}^{-2} \text{.s}^{-1} \rightarrow 60 \text{ n.frame}^{-1}$ 



**3. Spectrum example** 

Raw spectrum of a mono-energetic neutron beam of 20 MeV ( $\Phi = 10^7 \text{ n.cm}^{-2}.\text{s}^{-1}$ )



#### 4. Background study



#### 4. Background study

 $\rightarrow$  Background after the peak : simultaneous collision of a neutron in the diode



#### 4. Background study

 $\rightarrow$  Background after the peak : simultaneous collision of a neutron in the diode

 $\rightarrow$  Easily suppressed by the mean of a second Si-diode called « veto »



4. Background study

Raw spectrum of a monoenergetic neutron beam of 20 MeV ( $\Phi = 10^7 \text{ n.cm}^{-2}.\text{s}^{-1}$ )



#### 4. Background study

 $\rightarrow$  background before the peak : proton escapes by the side of the diode, leaving only a fraction of its energy (=lower energy reconstructed)

 $\rightarrow$  eliminated partially by veto. Completed with track projection



#### 4. Background study

 $\rightarrow$  background before the peak : proton escapes by the side of the diode, leaving only a fraction of its energy (=lower energy reconstructed)

 $\rightarrow$  eliminated partially by veto. Completed with track projection



#### 4. Background study

 $\rightarrow$  background before the peak : proton escapes by the side of the diode, leaving only a fraction of its energy (=lower energy reconstructed)

 $\rightarrow$  eliminated partially by veto. Completed with track projection



#### 4. Background study

 $\rightarrow$  4 cutoffs : track projection + veto + X<sup>2</sup> test + increasing dE/dX





 $\rightarrow$  protontherapy : simulation to estimate secondaries neutrons dose to tissues

→ ≠ models → ≠ results : **experimental validation necessary** 





19



 $\rightarrow$  PRT should allow us to differenciate these models

#### **Prospect :**

- test at CYRCÉ proton cyclotron @ 5-24 MeV (IPHC)
- measurement at IPHC Am-Be source



- measurement at AMANDE facility (IRSN) : neutron field from 2 keV to 20.5 MeV
- measurement at protontherapy center (contact with Centre Antoine Lacassagne, Nice @ 65, 235 MeV)
  - $\rightarrow$  looking forward for more centers to make more measurements
- other applications to investigate : industrial sterilization, cross section measurement, etc.
- new ideas to improve performances for future versions :
- $\bullet$  replace (CH<sub>2</sub>)<sub>n</sub> converter by a scintillator to improve resolution at thicker converter sizes
- extend energy range by adding more CMOS, modifying angle between CMOS and converter, etc.

### **GATE** activites @ IPHC

# Thank you for your attention !